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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/551,802	12/02/2005	Satoshi Sugahara	125471	6737
25944 7590 11/30/2007 OLIFF & BERRIDGE, PLC P.O. BOX 320850			EXAMINER	
			VALENTINE, JAMI M	
ALEXANDRIA, VA 22320-4850			ART UNIT	PAPER NUMBER
			2815	
			MAIL DATE	DELIVERY MODE
			11/30/2007	PAPER

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

		Application No.	Applicant(s)			
Office Action Summary						
		10/551,802	SUGAHARA ET AL.			
	Office Action Summary	Examiner	Art Unit			
	The MAILING DATE of this communication and	Jami M. Valentine, Ph.D.	2815			
Period fo	The MAILING DATE of this communication app or Reply	ears on the cover sheet with the c	orrespondence address			
VVHIC - Exte after - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPLY CHEVER IS LONGER, FROM THE MAILING DANSIONS of time may be available under the provisions of 37 CFR 1.13 SIX (6) MONTHS from the mailing date of this communication. Depriod for reply is specified above, the maximum statutory period were to reply within the set or extended period for reply will, by statute, reply received by the Office later than three months after the mailing ed patent term adjustment. See 37 CFR 1.704(b).	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be timulated will expire SIX (6) MONTHS from a cause the application to become AB ANDONE	I. lety filed the mailing date of this communication. D (35 U.S.C. § 133).			
Status						
1)🖂	I)⊠ Responsive to communication(s) filed on <u>06 September 2007</u> .					
2a)⊠	This action is FINAL. 2b) ☐ This action is non-final.					
3)	☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
	closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.					
Dispositi	on of Claims	,				
4) Claim(s) 35-99 is/are pending in the application. 4a) Of the above claim(s) is/are withdrawn from consideration. 5) □ Claim(s) is/are allowed. 6) □ Claim(s) 35,46,51,54,55,57 and 61 is/are rejected. 7) □ Claim(s) 22,36-45,47-50,52,53,56,58-60 and 62-99 is/are objected to. 8) □ Claim(s) are subject to restriction and/or election requirement.						
Applicati	on Papers					
10)⊠	The specification is objected to by the Examiner The drawing(s) filed on <u>06 September 2007</u> is/a Applicant may not request that any objection to the o Replacement drawing sheet(s) including the correcti The oath or declaration is objected to by the Example 1	re: a)⊠ accepted or b)☐ object drawing(s) be held in abeyance. See ion is required if the drawing(s) is obj	e 37 CFR 1.85(a). ected to. See 37 CFR 1.121(d).			
Priority u	ınder 35 U.S.C. § 119					
12) ⊠ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) ⊠ All b) ☐ Some * c) ☐ None of: 1. ☐ Certified copies of the priority documents have been received. 2. ☐ Certified copies of the priority documents have been received in Application No 3. ☒ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received.						
• • •						
Attachment	l(s) e of References Cited (PTO-892)	4) Interview Summary	(PTO-413)			
2) Notic	e of Draftsperson's Patent Drawing Review (PTO-948)	Paper No(s)/Mail Da	te			
	nation Disclosure Statement(s) (PTO/SB/08) r No(s)/Mail Date <u>8/14/07</u> .	5) Notice of Informal Page 6) Other:	atent Application			

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DETAILED ACTION

Status of the Application

1. Acknowledgement is made of the amendment received 9/6/07. Claims 1-51 and 54-99 are pending in this application. Claims 1-34 were previously withdrawn as being drawn to a nonelected group of claims. Claims 35, 37, 38, 40, 42, 43, 45-50, 56, 62-73 and 99 were amended and claims 52-53 were canceled in the amendment received 9/6/07.

Response to Arguments

2. Applicant's arguments filed 9/6/07 have been fully considered but they are moot in view of the new grounds of rejection.

Drawings

3. The objection to the drawings has been withdrawn in light of the amendment received 9/6/07.

Specification

4. The objections to the specification have been withdrawn in light of the amendment received 9/6/07.

Claim Objections

- 5. Claim 22 is objected to because of the following informalities: the preliminary amendment filed 9/30/05 amended claim 22 to recite "The memory element as claimed in claim 20, wherein..." In contrast, the amendment entered 9/6/07 recites claim 22 as "The memory element as claimed in claim 20 or 21, wherein..."
- 6. Appropriate correction is required.

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Claim Rejections - 35 USC § 112

7. The rejections under 35 U.S.C. 112, second paragraph have been withdrawn in light of the amendment received 9/6/07.

Claim Rejections - 35 USC § 102

- 8. The text of those sections of Title 35, U.S. Code not included in this action can be found in a prior Office action.
- 9. Claims 35, 46, 51, 54, 55, 57 and 61 are rejected under 35 U.S.C. 102(e) as being anticipated by Yoshida et al. (US Patent Application Publication No 2005/0117617) hereinafter referred to as Yoshida.
- 10. Per Claim 35 Yoshida (e.g. figure 2) discloses a device comprising
 - a ferromagnetic semiconductor layer (1)
 - a source (3) that injects carriers into the ferromagnetic semiconductor layer; and
 - a drain (4) that receives the carriers injected into the ferromagnetic semiconductor layer
 - a gate electrode (6) that applies a voltage for controlling conduction of the carriers
 flowing in the ferromagnetic semiconductor layer from the source to the drain.
- 11. Per Claim 46 Yoshida discloses the transistor of claim 35, including where the ferromagnetic semiconductor layer is a semiconductor with magnetic elements. [0067]
- 12. Per Claim 51 Yoshida discloses the transistor of claim 35, including an insulating layer (5) is interposed between the gate electrode (6) and the ferromagnetic semiconductor layer (1).
- 13. Per Claim 54 Yoshida discloses the transistor of claim 35, including where the transistor is formed on a substrate made of a semiconductor, a substrate having a semiconductor layer

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formed thereon, or a substrate having an insulating layer formed thereon (e.g. figure 2).

S source

1 p-type magnetic semiconductor layer

2 b-type magnetic semiconductor layer

8 drain

10 gate 7 source

circular-polarization spin-based laser source

Prior Art: Yoshida Figure 2

14. Per Claims 55, 57 and 61 Yoshida discloses the transistor of claim 54, including where the transistor is formed on the substrate; the junction interface of the source and the drain in the vicinity of the gate electrode is substantially perpendicular (and parallel) to the principal surface of the substrate; and the flowing direction of the carriers moving from the source to the drain is in a plane substantially parallel (and perpendicular) to the principal surface of the substrate (e.g. figure 2, the junction interface of the source and the drain in the vicinity of the gate electrode is both parallel and perpendicular to the principle surface of the substrate; Additionally, the flowing direction of the carriers moving from the source to the drain is in both a plane substantially parallel and one substantially perpendicular to the principal surface of the substrate.

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Cited Prior Art

15. The following prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Reference 1: US Patent Application Publication No 2006/0043443 by Sugahara et al.

Allowable Subject Matter

16. Claims 36-45, 47-50, 52-53, 56, 58-60 and 62-99 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Conclusion

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

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Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Jami M. Valentine, Ph.D. whose telephone number is (571) 272-

9786. The examiner can normally be reached on Mon-Thurs 8:30am-7pm EST.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Kenneth Parker can be reached on (571) 272-2298. The fax phone number for the

organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

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information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Jami M Valentine, Ph.D.

Examiner

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PRIMARY EXAMINER